

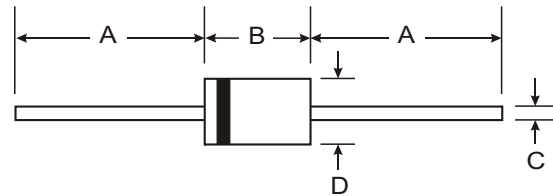
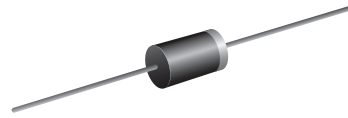
VOLTAGE RANGE: 50 - 1000V
CURRENT: 3.0 A

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Applications

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-201AD		
Dim	Min	Max
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	EGP 30A	EGP 30B	EGP 30D	EGP 30F	EGP 30G	EGP 30J	EGP 30K	EGP 30M	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	300	400	600	800	1000	V	
RMS Reverse Voltage	V _{R(RMS)}}	35	70	140	210	280	420	560	700	V	
Average Rectified Output Current (Note 1) @T _A = 55°C	I _O	3.0								A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	125					115				A
Forward Voltage @I _F = 3.0A	V _{FM}	1.0				1.3	1.7				V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _{RM}	5.0					120				μA
Reverse Recovery Time (Note 2)	t _{rr}	50					75				nS
Typical Junction Capacitance (Note 3)	C _j	75								pF	
Typical thermal resistance (NOTE 3)	R _{θJA} R _{θJL}	20					8				°C / W
Storage Temperature Range	T _{STG}	-65 to +150								°C	

- Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
 2. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See figure 5.
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES EGP30A THRU EGP30M

